

# High-voltage Amplifier Transistor (120V, 50mA)

## 2SC4102 / 2SC3906K / 2SC2389S

### ●Features

- 1) High breakdown voltage. ( $BV_{CEO} = 120V$ )
- 2) Complements the 2SA1579 / 2SA1514K / 2SA1038S.

### ●Absolute maximum ratings ( $T_a=25^\circ C$ )

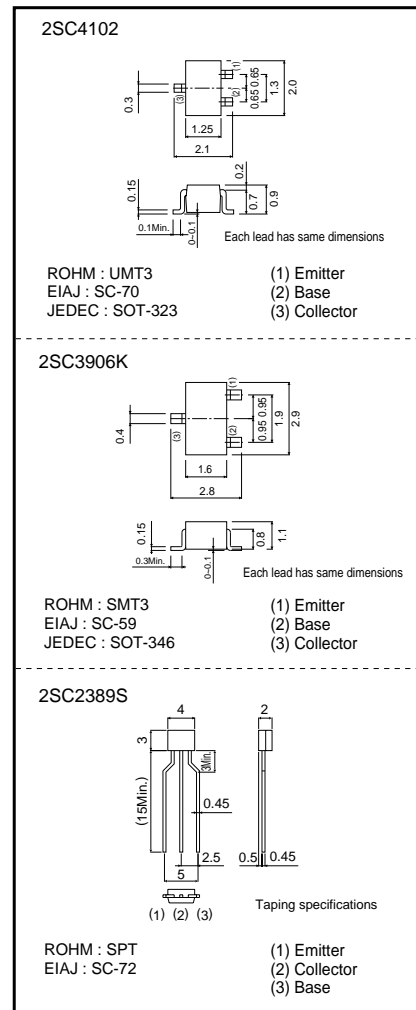
Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{CB0}$	120	V
Collector-emitter voltage	$V_{CEO}$	120	V
Emitter-base voltage	$V_{EB0}$	5	V
Collector current	$I_c$	50	mA
Collector power dissipation	Pc	2SC4102 / 2SC3906K	0.2
		2SC2389S	0.3
Junction temperature	$T_j$	150	$^\circ C$
Storage temperature	$T_{stg}$	-55~+150	$^\circ C$

### ●Packaging specifications and $h_{FE}$

Type	2SC4102	2SC3906K	2SC2389S
Package	UMT3	SMT3	SPT
$h_{FE}$	RS	RS	RS
Marking	T*	T*	-
Code	T106	T146	TP
Basic ordering unit (pieces)	3000	3000	5000

\*Denotes hFE

### ●External dimensions (Units : mm)



### ●Electrical characteristics ( $T_a=25^\circ C$ )

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$BV_{CB0}$	120	-	-	V	$I_c=50\mu A$
Collector-emitter breakdown voltage	$BV_{CEO}$	120	-	-	V	$I_c=1mA$
Emitter-base breakdown voltage	$BV_{EB0}$	5	-	-	V	$I_e=50\mu A$
Collector cutoff current	$I_{cbo}$	-	-	0.5	$\mu A$	$V_{CB}=100V$
Emitter cutoff current	$I_{ebo}$	-	-	0.5	$\mu A$	$V_{EB}=4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	-	0.5	V	$I_c/I_e=10mA/1mA$
DC current transfer ratio	$h_{FE}$	180	-	560	-	$V_{CE}=6V, I_c=2mA$
Transition frequency	$f_t$	-	140	-	MHz	$V_{CE}=12V, I_e=2mA, f=100MHz$
Output capacitance	$C_{ob}$	-	2.5	-	pF	$V_{CB}=12V, I_e=0A, f=1MHz$